

IEC TC 113 Nanotechnology for electrical and electronic products and systems

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Background Liaisons Graphene work US stakeholder involvement



United States National Committee of the IEC





INTERNATIONAL ELECTROTECHNICAL COMMISSION

TC 113 History

IEC Advisory Group formed to consider new area of standardization work in nano-electrotechnology in light of growth in nano-enabled electronics
IEC established new TC 113 in 2006
First plenary meeting in Frankfurt in 2007







TC 113 Priorities

Determine top standardization needs in the market
Establish liaisons with TC's and allied organizations
First deliverable – Blank detail specification for CNT's







TC 113 Working Group Structure

- JWG1, Terminology
- JWG2, Measurement and characterization
- WG3, Performance assessment
- WG7, Reliability assessment







TC 113 Working Group Structure

- WG8, Graphene related materials, CNT materials

- WG9, Nano-enabled photovoltaics, thin film organic nano-electronics, nanoscale contacts and interconnects
- WG10, Luminescent nanomaterials
- WG11, Nano-enabled energy storage





TC 113 Liaisons

- ISO TC 229, Nanotechnologies (JWG1, JWG2)
- IEC TC 1, Terminology (JWG1)
- IEC TC 21, Secondary cells and batteries (WG11)
- IEC TC 47, Semiconductor devices
- IEC TC 82, Solar photovoltaic energy systems (WG9)
- IEC TC 119, Printed electronics
- IEEE, SEMI, ANF





Blank detail specifications

- IEC 62565-3-1, Nanomanufacturing Material specifications, Part 3-1, Blank detail specification for graphene for electrotechnical applications (Committee Draft (CD) stage)
- IEC 62565-3-2, Nanomanufacturing Material specifications, Part 3-2, Sectional blank detail specification for nano-ink
 (Potential work item (PWI) stage)





Detail specifications

- IEC/TS 62565-3-3, Nanomanufacturing Material specifications, Part 3-3, Detail specification for single-layer graphene (PWI)
- IEC/TS 62565-3-4, Nanomanufacturing Material specifications, Part 3-4, Detail specification for bi-layer graphene (PWI)





- IEC/TS 62607-6-1: Graphene Measurement of sheet resistance of commercial graphene powders by the Four Probe Method (approved work item)
- IEC/TS 62607-6-2: Graphene Evaluation of the number of layers of graphene (approved work item)
- IEC/TS 62607-6-3: Graphene-Characterization of CVD graphene domains (CD)





- IEC/TS 62607-6-4: Graphene Surface conductance measurement using resonant cavity (published)
- IEC/TS 62607-6-5: Graphene sheet resistance and contact resistance measurement using the transmission line method (PWI)
- IEC/TS 62607-6-6: Graphene Uniformity of strain in graphene analyzed by Raman spectroscopy (PWI)





- IEC/TS 62607-6-7: Determination of specific surface area of graphene materials using methylene blue adsorption method (PWI)
- IEC/TS 62607-6-8: Graphene Measurement of sheet resistance by the four-point probe method (PWI)
- IEC/TS 62607-6-9: Graphene Measurement of sheet resistance by the non-contact Eddy current method (PWI)





- IEC/TS 62607-6-10: Graphene Measurement of sheet resistance by terahertz time-domain spectroscopy (PWI)
- IEC/TS 62607-6-11: Graphene Defect level of graphene analyzed by Raman spectroscopy (PWI)
- IEC/TS 62607-6-13: Determination of content of functional group of graphene materials using Boehm's titration method (PWI)





- IEC/TS 62607-6-14: Graphene Defect level analysis of graphene powder using Raman spectroscopy (PWI)
 ISO/TR 19733: Matrix of characterization and measurement methods for Graphene (PWI)
- ISO/TS 80004-13: Nanotechnologies Vocabulary -Part 13: Graphene and other two dimensional materials (Draft Technical Specification (DTS) stage)





Participate!

- Standards drive markets, so drive the standards!

- Manufacturer and customer stakeholders are critical

- Join the TC 113 TAG







Thank you!

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